## DECLARATION FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

SELF ALIGNED METHOD OF FORMING A SEMICONDUCTOR MEMORY ARRAY OF FLOATING GATE MEMORY CELLS WITH LOW RESISTANCE SOURCE REGIONS AND HIGH SOURCE COUPLING, AND A MEMORY ARRAY MADE THERBY

the specification of which (check one) is attached hereto or _X_ was filed on <u>July 26, 2001</u> as Application No. <u>09/916,555</u> and was amended on (if applicable).				
I hereby state that I hav including the claims, as	e reviewed and understand amended by any amendme	the contents of the above-identified specification, ent referred to above.		
I acknowledge the duty to disclose all information which is material to patentability as defined in 37 CFR § 1.56.  I hereby claim foreign priority benefits under 35 U.S.C. § 119(a)-(d) or § 365(b) of any foreign application(s) for patent or inventor's certificate, or § 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:				
Number	Country	Day/Month/Year Filed		
I hereby claim the bene 60/234,314	fit under 35 U.S.C. § 119(e September 20,	e) of any United States provisional application(s) below.		
Application Number	Filing Date			
60/242,096	October 19, 20	000		
Application Number	Filing Date			
_60/260,167	January 5, 200	· ·		
Application Number	Filing Date			
_60/275,517	March 12, 200			
Application Number	Filing Date	A		
_60/287,047	April 26, 2001			

I hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose all information which is material to patentability as defined in 37 CFR § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application:

Application Number	Filing Date	Status: Patented, Pending, Abandoned
		1
Application Number	Filing Date	Status: Patented, Pending, Abandoned
on information and belief a knowledge that willful fals	are believed to be true se statements and the 001 and that such will	of my own knowledge are true and that all statements made; and further that these statements were made with the like so made are punishable by fine or imprisonment or ful false statements may jeopardize the validity of the
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